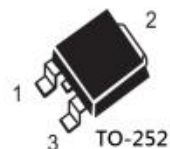
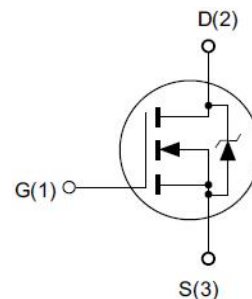


Features

- ◆ 500V, 5A, $R_{DS(ON)}(Typ.) = 1.35\Omega @ V_{GS} = 10V$.
- ◆ Low C_{rss}
- ◆ Fast Switching
- ◆ 100% Avalanche Tested

Application

- ◆ Adaptor
- ◆ Standby Power
- ◆ Switching power supply
- ◆ LED Power



Absolute Maximum Ratings $T_c = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-Source Voltage ^a	500	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-Continuous, $T_c = 25^\circ C$	5	A
	Drain Current-Continuous, $T_c = 100^\circ C$	3.2	A
I_{DM}	Drain Current-Pulsed ^b	20	A
P_D	Maximum Power Dissipation @ $T_J = 25^\circ C$	98	W
dv/dt	Peak Diode Recovery dv/dt ^c	5	V/ns
E_{AS}	Single Pulsed Avalanche Energy ^d	125	mJ
T_J, T_{STG}	Operating and Store Temperature Range	150, -55 to 150	$^\circ C$

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.27	$^\circ C/W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	60	$^\circ C/W$

Electrical Characteristics $T_J = 25^\circ C$ unless otherwise noted

■ Off Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	500	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 500V, V_{GS} = 0V$	-	-	1	μA
I_{GSS}	Forward Gate Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 30V$	-	-	± 100	nA

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.0	3.0	4.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10V, I_D = 2.5A$	-	1.35	1.6	Ω
g_{fs}	Forward Transconductance	$V_{DS} = 15V, I_D = 2.5A$	-	3.9	-	S

■ Dynamic Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
R_g	Gate Resistance	$f = 1.0MHz$	-	2.1	-	Ω
C_{iss}	Input Capacitance	$V_{DS} = 25V,$ $V_{GS} = 0V,$ $f = 1.0MHz$	-	615	-	pF
C_{oss}	Output Capacitance		-	67	-	pF
C_{rss}	Reverse Transfer Capacitance		-	10	-	pF

■ On Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 250V, I_D = 2A,$ $V_{GS} = 10V, R_g = 24\Omega$	-	12	-	ns
t_r	Turn-On Rise Time		-	17	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	45	-	ns
t_f	Turn-Off Fall Time		-	25	-	ns
Q_g	Total Gate Charge	$V_{DS} = 250V, I_D = 2A,$ $V_{GS} = 10V$	-	14	-	nC
Q_{gs}	Gate-Source Charge		-	3.3	-	nC
Q_{gd}	Gate-Drain Charge		-	4.0	-	nC

■ Drain-Source Diode Characteristics

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
I_S	Drain-Source Diode Forward Continuous Current	$V_{GS} = 0V$	-	-	5	A
I_{SM}	Maximum Pulsed Current	$V_{GS} = 0V$	-	-	20	A
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0V, I_S = 5A$	-	-	1.2	V
T_{rr}	Body Diode Reverse Recovery Time	$I_S = 5A, V_{GS} = 0V$ $dI_F/dt = 100A/\mu s$	-	340	-	ns
Q_{rr}	Body Diode Reverse Recovery Charge		-	2.9	-	μC

Notes:

- $T_J = +25^\circ C$ to $+150^\circ C$
- Repetitive rating; pulse width limited by maximum junction temperature.
- $I_{SD} = 5A, dI_F/dt \leq 100A/\mu s, V_{DD} \leq BV_{DS},$ Start $T_J = 25^\circ C$.
- $L = 10mH, V_{DD} = 50V, I_{AS} = 5A, R_g = 25\Omega$ Starting $T_J = 25^\circ C$.

■ Characteristic Curve

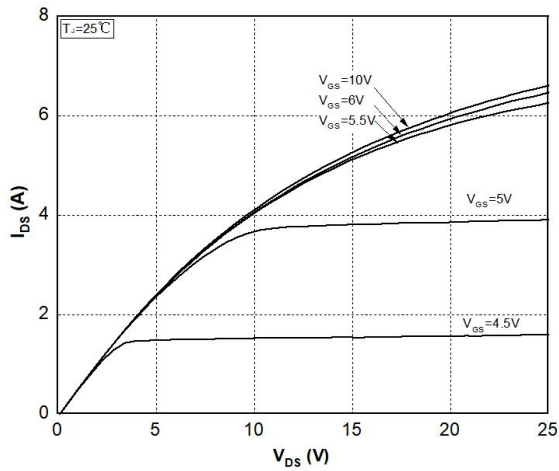


Figure 1. Typical Output Characteristics

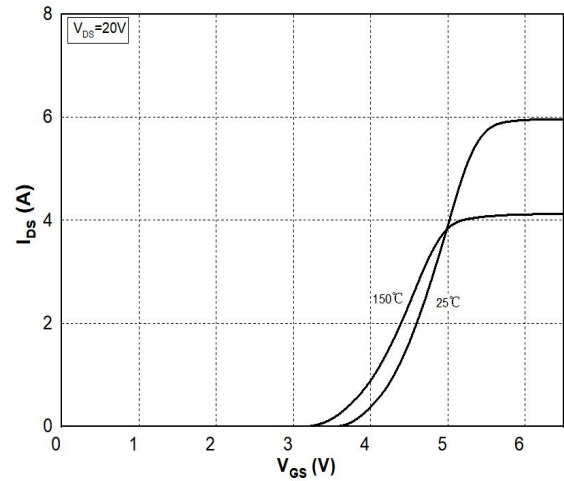


Figure 2. Typical Transfer Characteristics

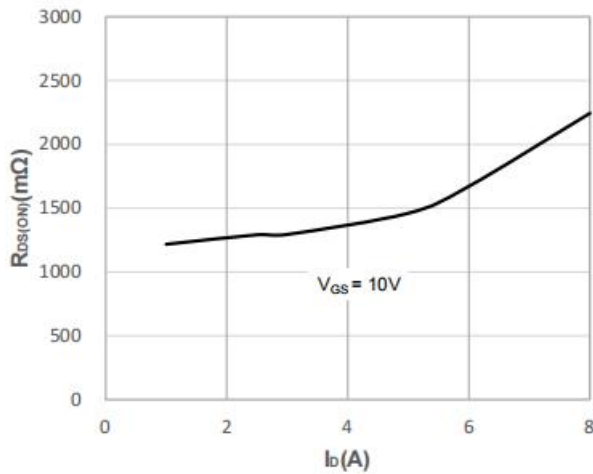


Figure 3. On- Resistance vs. Drain Current

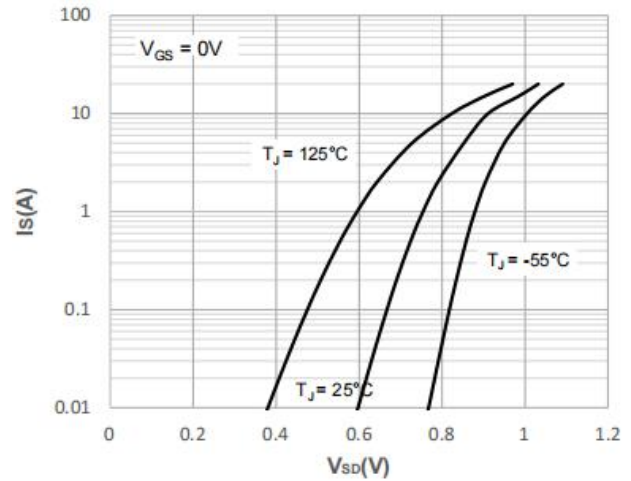


Figure 4. Body-Diode Characteristics

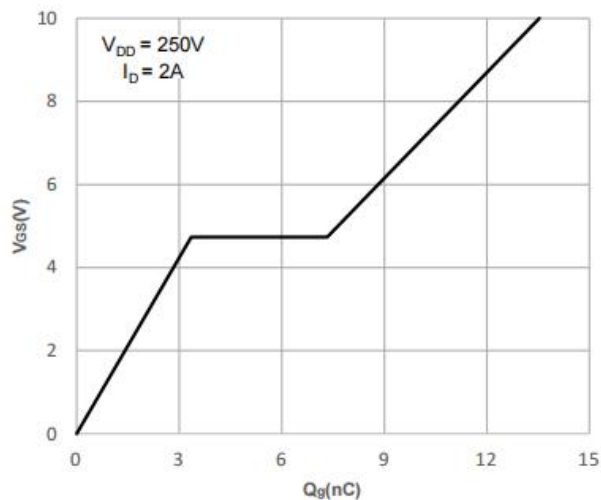


Figure 5. Gate-Charge Characteristics

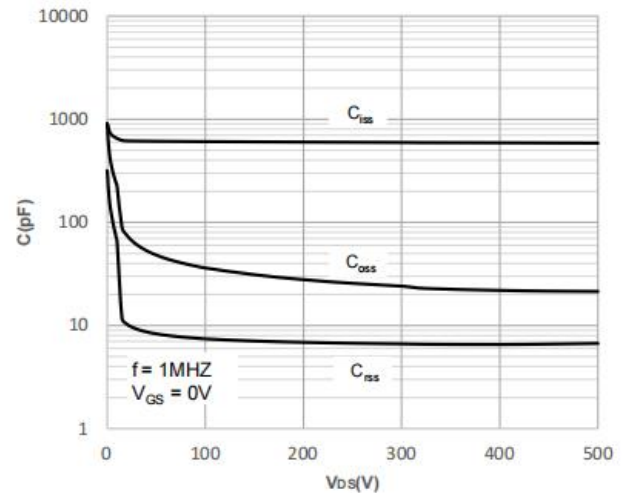


Figure 6. Capacitance Characteristics

■ Characteristic Curve

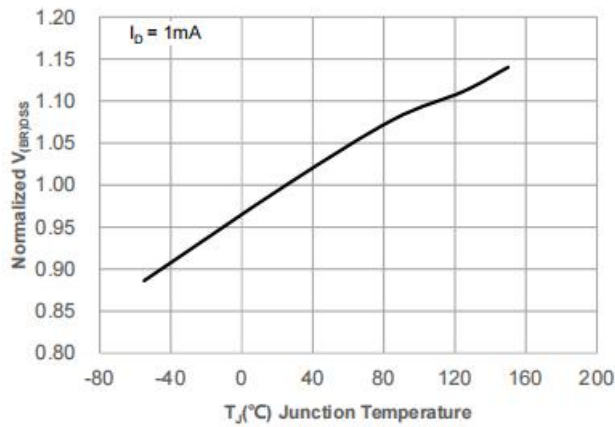


Figure 7. Normalized Breakdown voltage vs. Junction Temperature

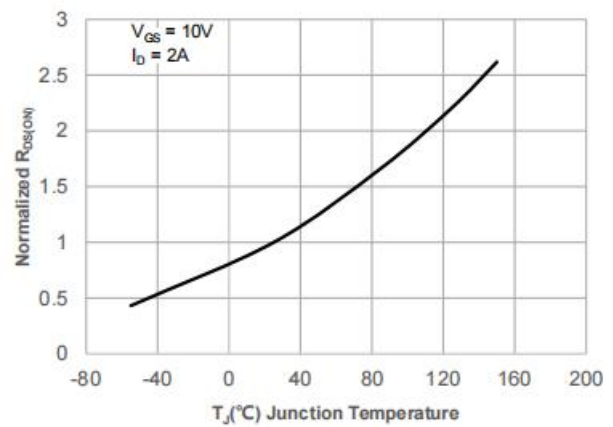


Figure 8. Normalized on Resistance vs. Junction Temperature

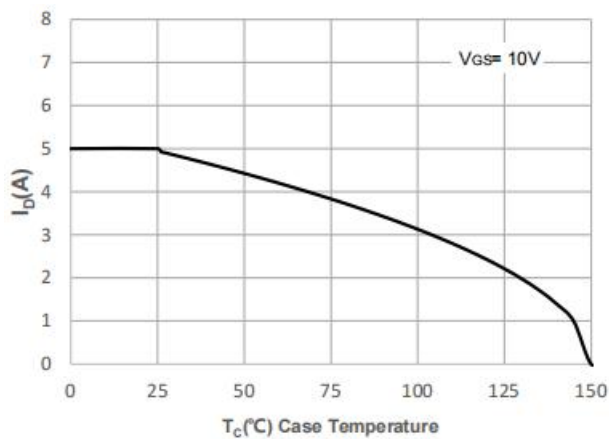


Figure 9: Maximum Continuous Drain Current vs. Case Temperature

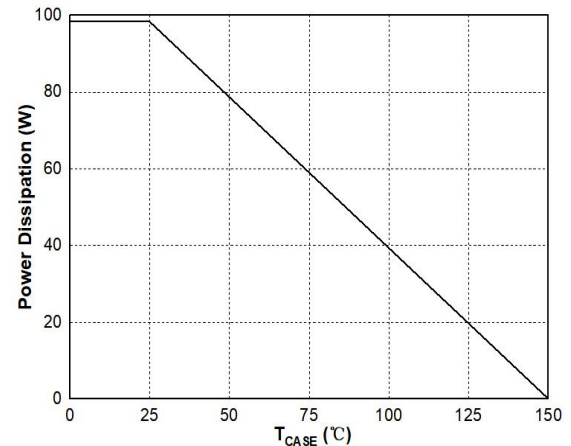


Figure 10: Maximum Power Dissipation vs Case Temperature

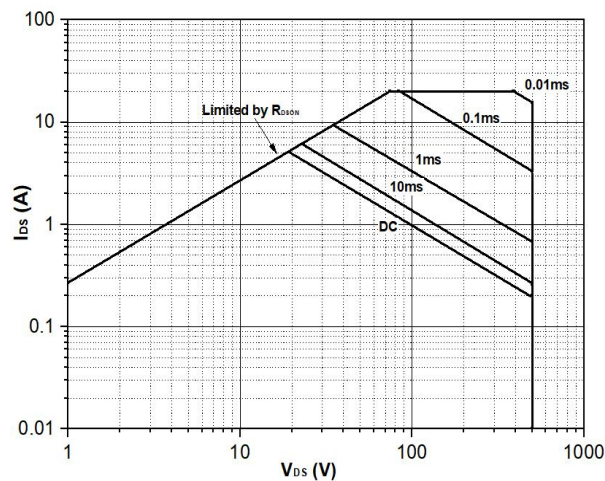


Figure 11. Maximum Safe Operating Area

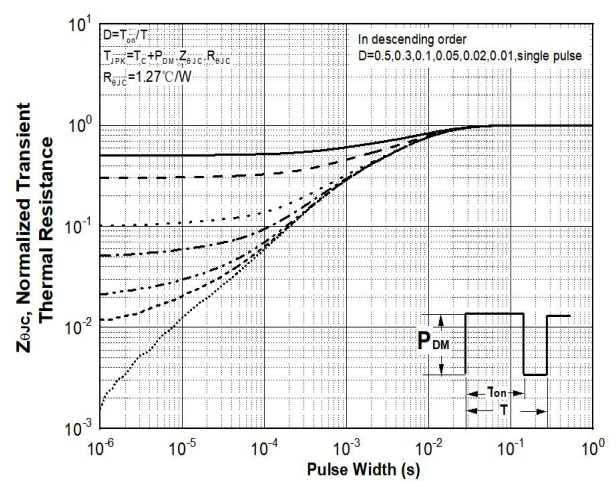
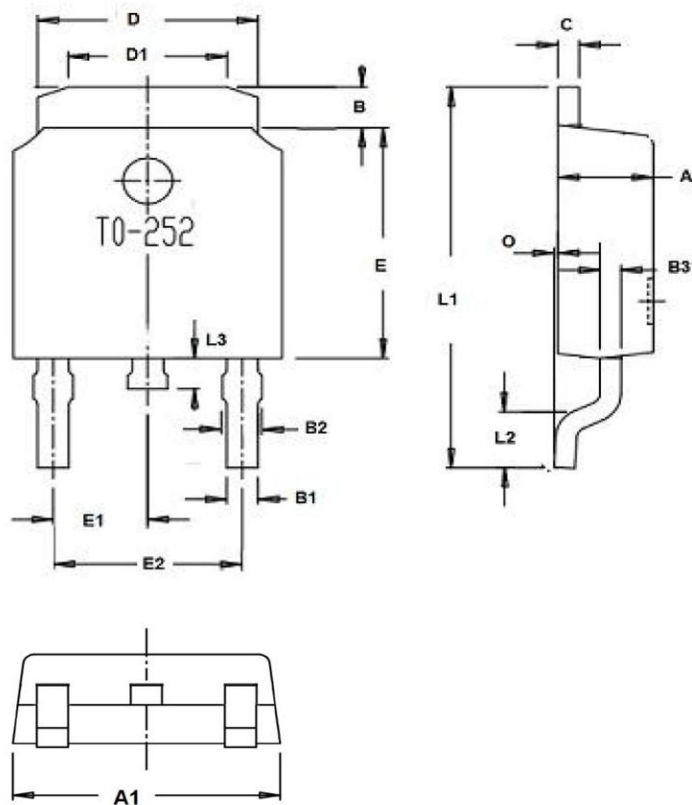


Figure 12: Normalized Maximum Transient Thermal Impedance

■ Package Information

TO-252



Dim.	Min.	Max.
A	2.1	2.5
A1	6.3	6.9
B	0.96	1.42
B1	0.74	0.86
B2	0.74	0.94
C	Typ0.5	
D	5.33	5.53
D1	3.65	4.05
E	6.0	6.2
E1	Typ2.29	
E2	Typ4.58	
O	0	0.15
L1	9.9	10.5
L2	Typ1.65	
L3	0.6	1.0
All Dimensions in millimeter		